

### Fast Recovery Rectifier Diodes

... Designed for use in switching power supplies, inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- \* Glass Passivated chip junctions
- \* Low Reverse Leakage Current
- \* Fast Switching for High Efficiency
- \* 150 °C Operating Junction Temperature
- \* Low Forward Voltage , High Current Capability
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

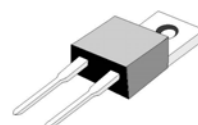
\* *Pb Free*

\* *In compliance with EU RoHs directives*



**FAST RECOVERY  
RECTIFIERS**

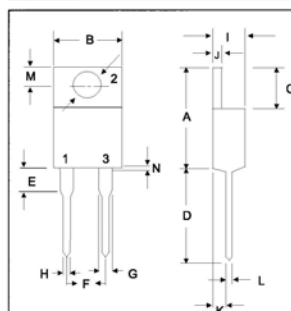
**8 AMPERES  
50 -- 200 VOLTS**



**TO-220A**

### MAXIMUM RATINGS

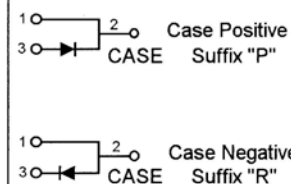
Characteristic	Symbol	F08A				Unit
		05	10	15	20	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	50	100	150	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	V
Average Rectifier Forward Current	$I_{F(AV)}$	8.0				A
Non-Repetitive Peak Surge Current ( Surge applied at rate load conditions halfwave,single phase,60Hz )	$I_{FSM}$	150				A
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	- 65 to + 150				°C



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	16.00
B	9.78	10.42
C	5.02	6.60
D	13.00	14.62
E	3.10	4.19
F	2.41	2.67
G	1.10	1.67
H	0.69	1.01
I	3.21	4.98
J	1.14	1.40
K	2.20	3.30
L	0.28	0.61
M	2.48	3.00
O	3.50	4.00

### ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	F08A				Unit
		05	10	15	20	
Maximum Instantaneous Forward Voltage ( $I_F=8.0$ Amp, $T_C = 25$ °C)	$V_F$	1.30				V
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25$ °C) ( Rated DC Voltage, $T_C = 100$ °C)	$I_R$	10 500				uA
Reverse Recovery Time ( $I_F = 0.5$ A, $I_R = 1.0$ A , $I_{rr} = 0.25$ A )	$T_{rr}$	150				ns
Typical Junction Capacitance ( Reverse Voltage of 4 volts & f=1 MHz)	$C_P$	120				pF



# F08A05 Thru F08A20

FIG-1 TYPICAL FORWARD CHARACTERISTICS

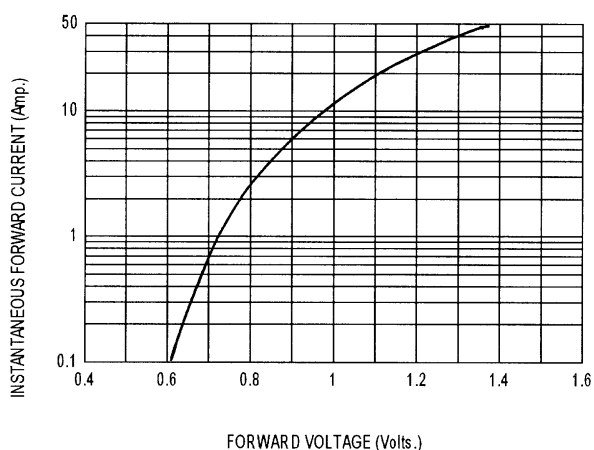


FIG-2 TYPICAL REVERSE CHARACTERISTICS

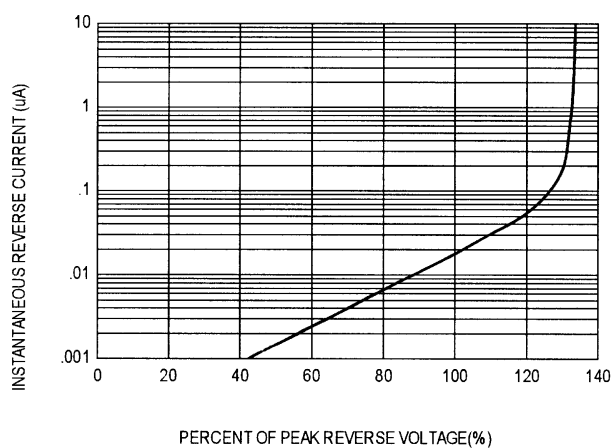


FIG-3 FORWARD CURRENT DERATING CURVE

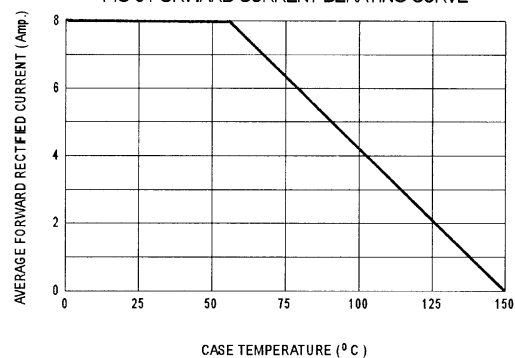


FIG-4 TYPICAL JUNCTION CAPACITANCE

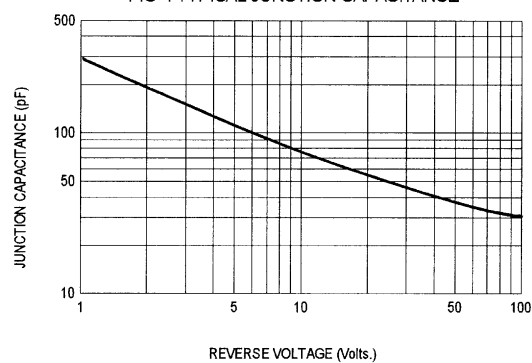
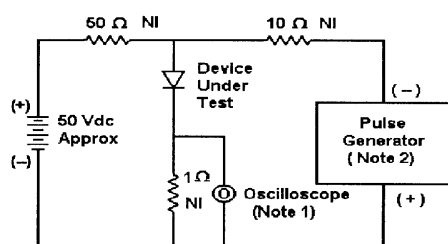
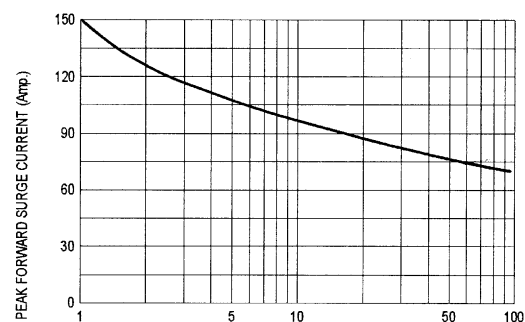
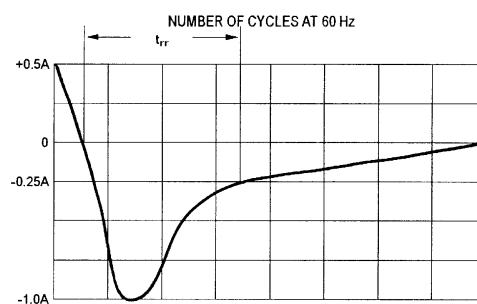


FIG-5 PEAK FORWARD SURGE CURRENT



- Notes:
1. Rise Time = 7 ns max. Input Impedance = 1 MΩ, 22 pF
  2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 50 ns/div

Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

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